# 74AHC2G126-Q100; 74AHCT2G126-Q100

Dual buffer/line driver; 3-state

Rev. 2 — 19 November 2018

Product data sheet

# 1. General description

The 74AHC2G126-Q100 and 74AHCT2G126-Q100 are high-speed Si-gate CMOS devices. They provide a dual non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (nOE). A LOW at nOE causes the output to assume a high-impedance OFF-state.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF; R = 0 Ω)

# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74AHC2G126DP-Q100	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
74AHC2G126DC-Q100	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package;	SOT765-1
74AHCT2G126DC-Q100			8 leads; body width 2.3 mm	



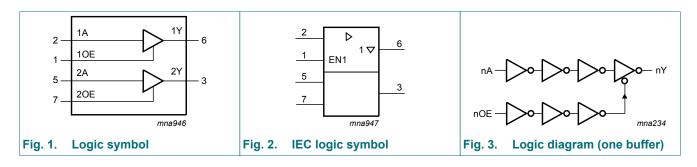
# 4. Marking

### Table 2. Marking codes

Type number	Marking[1]
74AHC2G126DP-Q100	A26
74AHC2G126DC-Q100	A26
74AHCT2G126DC-Q100	C26

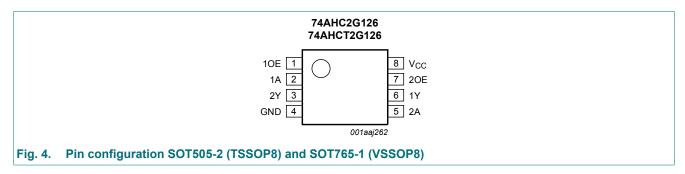
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

# 6.1. Pinning



### 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
10E, 20E	1, 7	output enable input (active HIGH)
1A, 2A	2, 5	data input
GND	4	ground (0 V)
1Y, 2Y	6, 3	data output
V <sub>CC</sub>	8	supply voltage

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# 7. Functional description

### **Table 4. Function table**

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$ 

	Input	Output
nOE	nA	nY
Н	L	L
Н	Н	Н
L	X	Z

# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	[1]	-20	-	mA
I <sub>OK</sub>	output clamping current	$V_{O}$ < -0.5 V or $V_{O}$ > $V_{CC}$ + 0.5 V	[1]	-	±20	mA
Io	output current	-0.5 V < V <sub>O</sub> < V <sub>CC</sub> + 0.5 V		-	±25	mA
I <sub>CC</sub>	supply current			-	75	mA
I <sub>GND</sub>	ground current			-75	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74AHC2G126-Q100			74AH	-Q100	Unit	
			Min	Тур	Max	Min	Тур	Max	
$V_{CC}$	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	-	-	100	-	-	-	ns/V
	fall rate	V <sub>CC</sub> = 5.0 V ± 0.5 V	-	-	20	-	-	20	ns/V

<sup>[2]</sup> For TSSOP8 package: above 55 °C the value of P<sub>tot</sub> derates linearly with 2.5 mW/K. For VSSOP8 package: above 110 °C the value of P<sub>tot</sub> derates linearly with 8 mW/K.

# 10. Static characteristics

### **Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC2	G126-Q100							1		
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_O = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.8	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 50 $\mu$ A; $V_{CC}$ = 3.0 $V$	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		$I_{O}$ = 8.0 mA; $V_{CC}$ = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	0.25	-	2.5	-	10	μΑ
I <sub>I</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μΑ
Cı	input capacitance		-	1.5	10	-	10	-	10	pF

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHCT	2G126-Q100					•		1	'	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V
	I <sub>O</sub> = -8.0 mA	3.94	-	-	3.8	-	3.70	-	V	
V <sub>OL</sub> LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$									
	output voltage	Ι <sub>Ο</sub> = 50 μΑ	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	0.25	-	2.5	-	10	μΑ
l <sub>l</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μΑ
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I$ = 3.4 V; other inputs at $V_{CC}$ or GND; $I_O$ = 0 A; $V_{CC}$ = 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
C <sub>I</sub>	input capacitance		-	1.5	10	-	10	-	10	pF

# 11. Dynamic characteristics

### **Table 8. Dynamic characteristics**

GND = 0 V; for test circuit see Fig. 7.

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	1
74AHC2	G126-Q100									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5 [1								
	delay	V <sub>CC</sub> = 3.0 V to 3.6 V [2]								
	C <sub>L</sub> = 15 pF	-	4.7	8.0	1.0	9.5	1.0	11.5	ns	
	C <sub>L</sub> = 50 pF	-	6.6	11.5	1.0	13.0	1.0	14.5	ns	
		V <sub>CC</sub> = 4.5 V to 5.5 V [3]								
		C <sub>L</sub> = 15 pF	-	3.4	5.5	1.0	6.5	1.0	7.0	ns
		C <sub>L</sub> = 50 pF	-	4.8	7.5	1.0	8.5	1.0	9.5	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 6 [1]								
		V <sub>CC</sub> = 3.0 V to 3.6 V [2]								
		C <sub>L</sub> = 15 pF	-	5.0	8.0	1.0	9.5	1.0	11.5	ns
		C <sub>L</sub> = 50 pF	-	6.9	11.5	1.0	13.0	1.0	14.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [3]								
		C <sub>L</sub> = 15 pF	-	3.6	5.1	1.0	6.0	1.0	6.5	ns
		C <sub>L</sub> = 50 pF	-	4.9	7.5	1.0	9.0	1.0	9.5	ns

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Max	Min	Max	
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 6	[1]								
		V <sub>CC</sub> = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	6.0	9.7	1.0	11.5	1.0	12.5	ns
		C <sub>L</sub> = 50 pF		-	8.3	13.2	1.0	15.0	1.0	16.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	4.1	6.8	1.0	8.0	1.0	8.5	ns
		C <sub>L</sub> = 50 pF		-	5.7	8.8	1.0	10.0	1.0	11.0	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; $C_L$ = 50 pF; $f_i$ = 1 MHz; $V_I$ = GND to $V_{CC}$	[4]	-	10	-	-	-	-	-	pF
74AHCT	2G126-Q100					'				1	
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5	[1]								
	delay	V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.4	5.5	1.0	6.5	1.0	7.0	ns
		C <sub>L</sub> = 50 pF		-	4.8	7.5	1.0	8.5	1.0	9.5	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 6	[1]								
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.9	5.1	1.0	6.0	1.0	6.5	ns
		C <sub>L</sub> = 50 pF		-	5.1	7.5	1.0	9.0	1.0	9.5	ns
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 6	[1]								
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	4.5	6.8	1.0	8.0	1.0	8.5	ns
		C <sub>L</sub> = 50 pF		-	6.1	8.8	1.0	10.0	1.0	11.0	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}$ ; $f_i = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}$	[4]	-	10	-	-	-	-	-	pF

- $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ ;  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ ;  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ . Typical values are measured at  $V_{CC}$  = 3.3 V.

- Typical values are measured at  $V_{CC}$  = 5.0 V.  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_0)$  where:

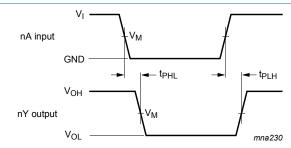
 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in Volts.

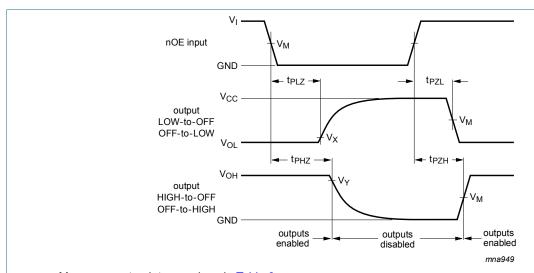
### 11.1. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 5. Input (nA) to output (nY) propagation delays



Measurement points are given in <u>Table 9</u>.

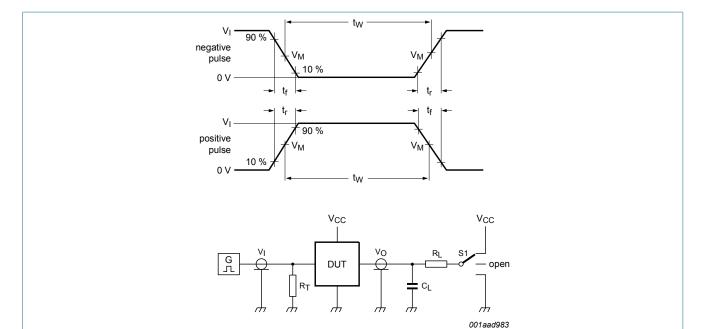
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 6. Enable and disable times

**Table 9. Measurement points** 

Туре	Input	Output						
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>				
74AHC2G126-Q100	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V				
74AHCT2G126-Q100	1.5 V	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V				

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Test data is given in Table 10.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_L$  = Load resistance.

S1 = Test selection switch.

### Fig. 7. Test circuit for measuring switching times

Table 10. Test data

Туре	Input		Load		S1 position		
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	C <sub>L</sub>	$R_L$	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	$t_{PZL}$ , $t_{PLZ}$
74AHC2G126-Q100	V <sub>CC</sub>	≤ 3 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>
74AHCT2G126-Q100	3 V	≤ 3 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>

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# 12. Package outline

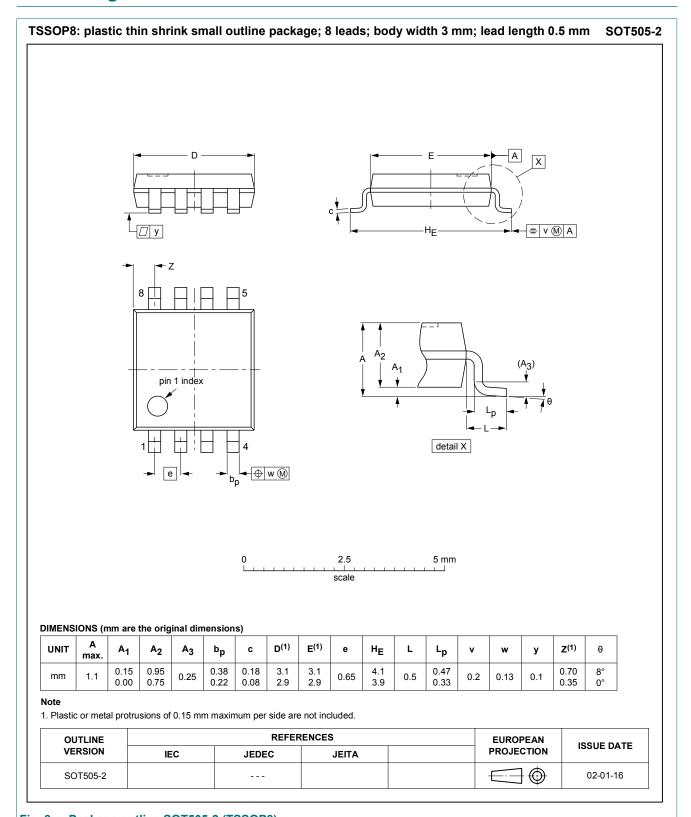
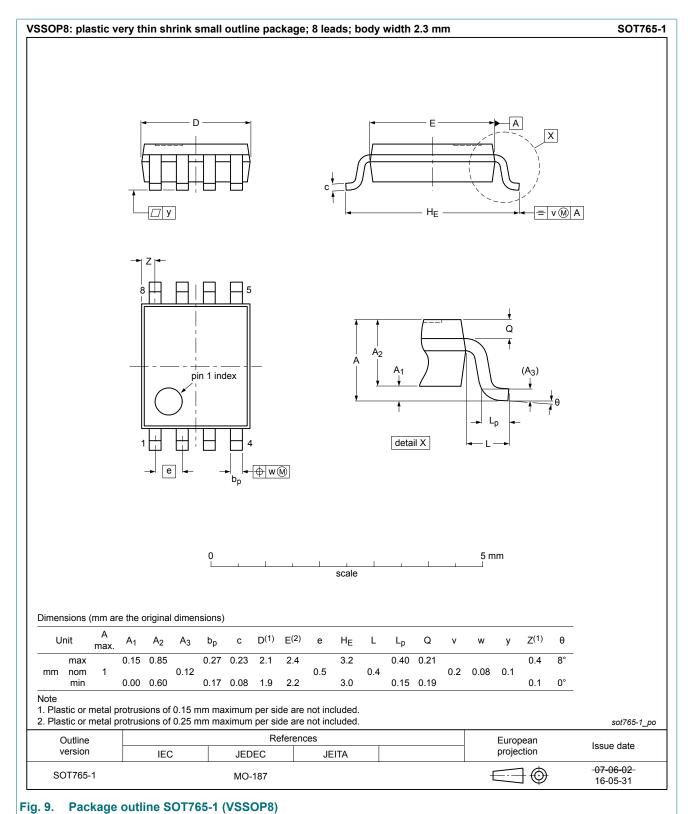


Fig. 8. Package outline SOT505-2 (TSSOP8)



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# 13. Abbreviations

### **Table 11. Abbreviations**

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

### **Table 12. Revision history**

Tuble 12. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AHC_AHCT2G126_Q100 v.2	20181119	Product data sheet	-	74AHC_AHCT2G126_Q100 v.1			
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type numbers 74AHCT2G126DP (SOT505-2/TSSOP8), 74AHC2G126GD and 74AHCT2G126GD (SOT996-2/XSON8) removed.</li> </ul>						
74AHC_AHCT2G126_Q100 v.1	20140311	Product data sheet	-	-			

## 15. Legal information

### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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